

## MOSFET Maximum Ratings T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>DSS</sub>	Drain to Source Voltage	25	V
V <sub>GS</sub>	Gate to Source Voltage	8	V
I <sub>D</sub> Drain Current Continuous Pulsed		0.22	•
		0.65	— A
PD	Power Dissipation	0.3	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	-55 to +150	°C
ESD	Electrostatic Discharge Rating MIL-STD-883D Human Body Model(100 pF / 1500 W)	6.0	kV
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	415	°C/W

## **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDG6301N	FDG6301N_F085	SC70-6	7"	8mm	3000 units

Notes:

3: Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%.

<sup>1:</sup> R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θJC</sub> is guaranteed by design, while R<sub>θJA</sub> is determined by the board design. R<sub>θJA</sub> = 415 <sup>o</sup>C/W on minimum pad mounting on FR-4 board in still air

<sup>2:</sup> A suffix as "...F085P" has been temporarily introduced in order to manage a double source strategy as Fairchild has officially announced in Aug 2014.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Cha	racteristics					
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V	25	-	-	V
	Zara Cata Valtaga Drain Current	V <sub>DS</sub> = 20V,	-	-	1	A
IDSS	Zero Gate Voltage Drain Current	$V_{GS} = 0V$ $T_J = 55^{\circ}C$	-	-	10	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	V <sub>GS</sub> = ±8V	-	-	±100	nA
<b>On Cha</b>	racteristics					
On Cha	racteristics		_			
	Gate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250μA	0.65	0.85	1.5	V
<b>On Cha</b> V <sub>GS(th)</sub>		I <sub>D</sub> = 0.22A, V <sub>GS</sub> = 4.5V	0.65	2.6	4	V
V <sub>GS(th)</sub>			0.65			V
	Gate to Source Threshold Voltage	I <sub>D</sub> = 0.22A, V <sub>GS</sub> = 4.5V	-	2.6	4	-
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$I_{D} = 0.22A, V_{GS} = 4.5V$ $I_{D} = 0.19A, V_{GS} = 2.7V$ $I_{D} = 0.22A, V_{GS} = 4.5V$	-	2.6 3.7	4 5	-

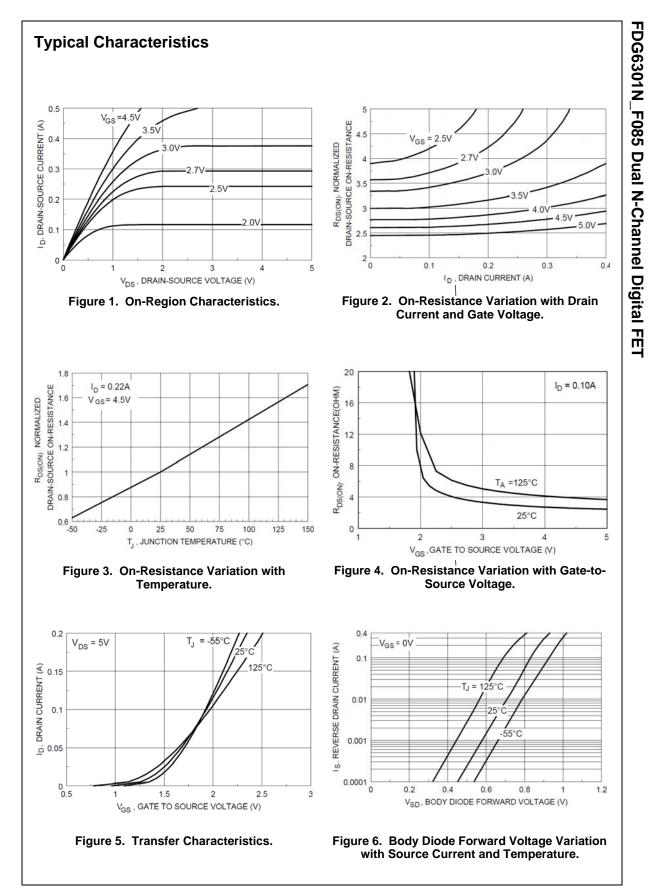
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V, f = 1MHz		-	9.5	-	pF
C <sub>oss</sub>	Output Capacitance			-	6	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	1.3	-	pF
Q <sub>g(TOT)</sub>	Total Gate Charge at -4.5V	V <sub>GS</sub> = 0 to 4.5V	)	-	0.29	0.4	nC
Q <sub>gs</sub>	Gate to Source Gate Charge	V <sub>DD</sub> = 5V I <sub>D</sub> = 0.22A		-	0.12	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	0.03	-	nC

# **Switching Characteristics**

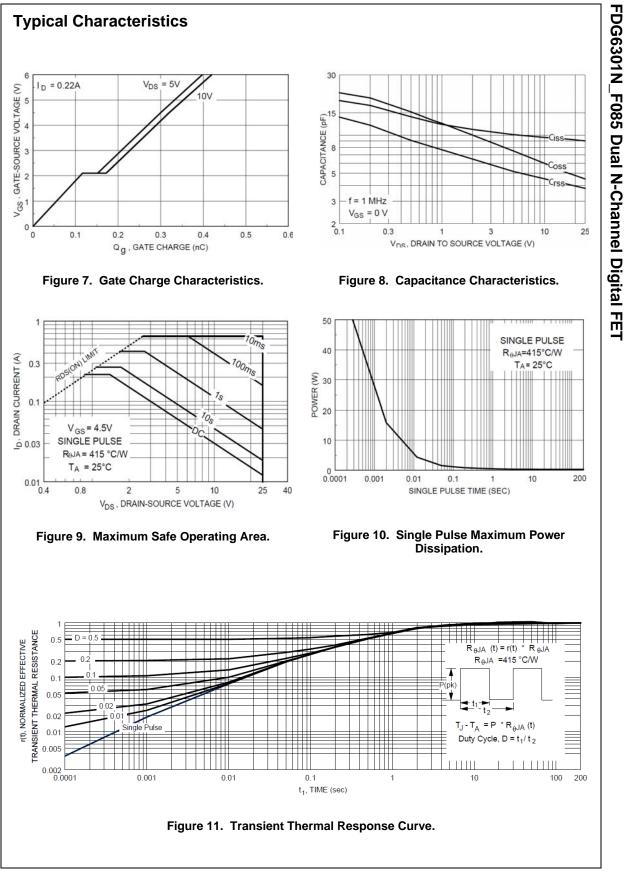
t <sub>d(on)</sub>	Turn-On Delay Time	N/ 51/1 0.54	-	5	10	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 5V, I <sub>D</sub> = 0.5A V <sub>GS</sub> = 4.5V, R <sub>GEN</sub> = 50Ω	-	4.5	10	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 4.3V, R_{GEN} = 50S2$	-	4	8	ns
t <sub>f</sub>	Fall Time		-	3.2	7	ns

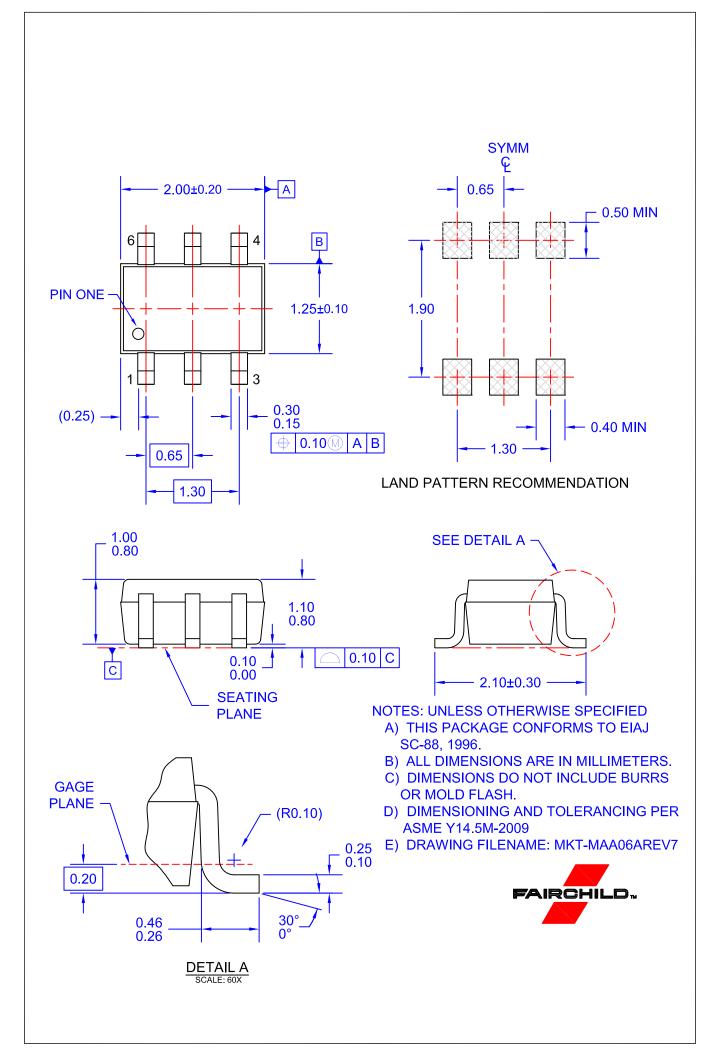
## **Drain-Source Diode Characteristics**

I <sub>S</sub>	Maximum Continuous Source Current		-	-	0.25	А
V <sub>SD</sub>	Source to Drain Diode Voltage	I <sub>SD</sub> = 0.25A, V <sub>GS</sub> = 0V	-	0.8	1.2	V



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